RENESAS

HZN6.8Z4MFA

Silicon Planar Zener Diode for Surge Absorb

REJ03G0205-0100Z Rev.1.00 Mar.29.2004

Features

- HZN6.8Z4MFA has four devices in a monolithic, and can absorb surge.
- Low capacitance (C = 4.0 pF Typ / 4.5 pF max) and can protect ESD of signal line.
- VSON-5T Package is suitable for high density surface mounting.

Ordering Information

Туре No.	Laser Mark	Package Code
HZN6.8Z4MFA	N2	VSON-5T

Pin Arrangement

		Anode
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Absolute Maximum Ratings

				(Ta = 25°C)
Item	Symbol	Value	Unit	
Power dissipation	Pd *	150	mW	
Junction temperature	Tj	150	°C	
Storage temperature	Tstg	–55 to +150	°C	

Note: Four device total, See Fig.2.

Electrical Characteristics *¹

 $(Ta = 25^{\circ}C)$

Item	Symbol	Min	Тур	Max	Unit	Test Condition
Zener voltage	Vz	6.47	_	7.00	V	$I_Z = 5 \text{ mA}, 40 \text{ ms pulse}$
Reverse current	I _R	_	_	2	μΑ	V _R = 3.5 V
Capacitance	С	_	4.0	4.5	pF	$V_{R} = 0 V, f = 1 MHz$
Dynamic resistance	r _d	_	_	30	Ω	$I_Z = 5 \text{ mA}$
ESD-Capability * ²	_	8	—		kV	C = 150 pF, R = 330 Ω , Both forward and reverse direction 10 pulse

Notes: 1. Per one device.

2. Failure criterion ; $I_R>2~\mu A$ at V_R = 3.5 V.

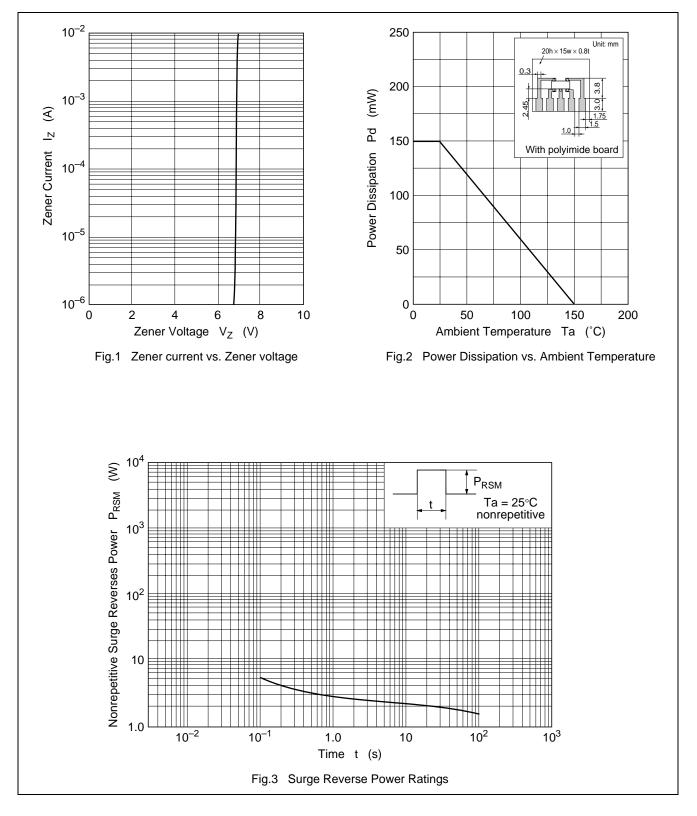
3. Between cathode and anode.

Month Code

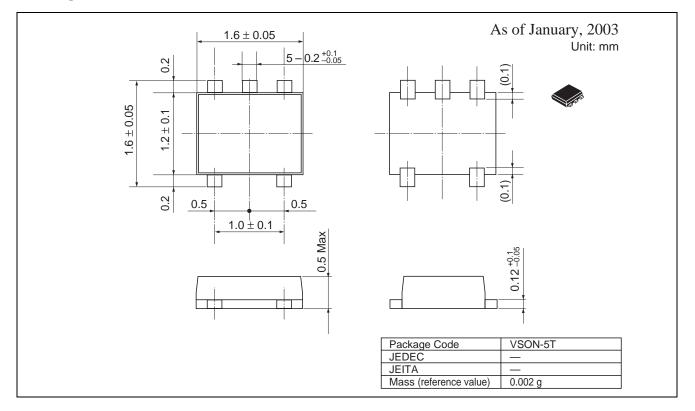
	Assemble			Assemble	
Month of Manufacture	JAPAN	MALAYSIA	Month of Manufacture	JAPAN	MALAYSIA
January	А	1	July	G	7
February	В	2	August	Н	8
March	С	3	September	J	9
April	D	4	October	К	W
Мау	E	5	November	L	Х
June	F	6	December	М	Y



Main Characteristic



Package Dimensions





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